NSN 5961-01-243-8476

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-243-8476 **Inclosure Material:** Ceramic **Overall Length:** 0.785 inches **Terminal Length:** 0.100 inches **Overall Height:** 0.200 inches **Overall Width:** 0.325 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-116 **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 35.0 drain to source voltage all transistor and 35.0 drain to gate voltage all transistor **Current Rating Per Characteristic:** 2.00 amperes drain current all transistor and 3.00 amperes off-state current, peak all transistor **Power Rating Per Characteristic:** 4.0 watts total device dissipation all transistor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 14 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No